

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			V _{DSS}	20	V
Gate-Source Voltage			V _{GSS}	±12	V
Continuous Drain Current (Note 6) V _{GS} = 10V	Steady State	T _A = +25°C T _A = +70°C	ID	3.5 3.0	A
Maximum Continuous Body Diode Forward Current (Note 6)			Is	1.0	A
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%) (Note 6)			I _{DM}	20	А

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)		PD	0.5	mW
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	R _{0JA}	259	°C/W
Total Power Dissipation (Note 6)		PD	0.7	mW
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	R _{0JA}	175	°C/W
Operating and Storage Temperature Range		T _{J,} T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

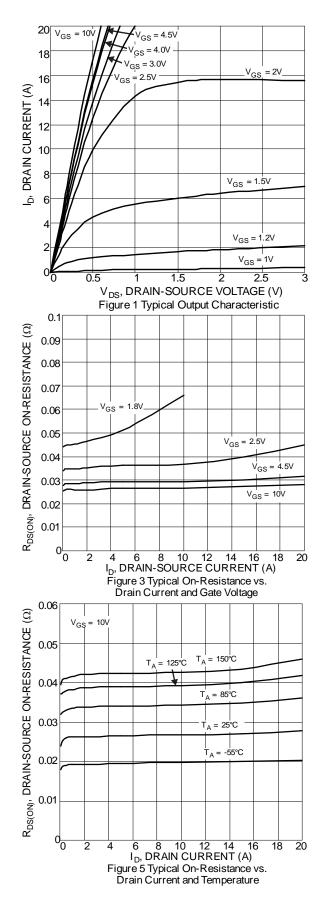
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)				•			
Drain-Source Breakdown Voltage	BV _{DSS}	20	_	—	V	$V_{GS} = 0V, I_D = 250\mu A$	
Zero Gate Voltage Drain Current	I _{DSS}	_		1	μA	$V_{DS} = 20V, V_{GS} = 0V$	
Gate-Source Leakage	Igss	_	-	±100	nA	$V_{GS} = \pm 12V$, $V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V _{GS(TH)}	0.4	—	1.2	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	
Static Drain-Source On-Resistance			31.5	42	mΩ	$V_{GS} = 10V, I_D = 3A$	
	P		32	45		$V_{GS} = 4.5V, I_D = 2A$	
	R _{DS(ON)}	_	40.5	60	1112	$V_{GS} = 2.5V, I_D = 2A$	
			48	91		V _{GS} = 1.8V, I _D = 1A	
Diode Forward Voltage	V _{SD}	_	0.78	1.2	V	$V_{GS} = 0V, I_{S} = 1A$	
DYNAMIC CHARACTERISTICS (Note 8)			•	•			
Input Capacitance	C _{iss}	—	281	_	pF		
Output Capacitance	Coss	—	50	—	pF	− V _{DS} = 10V, V _{GS} = 0V − f = 1.0MHz	
Reverse Transfer Capacitance	C _{rss}	_	39	_	pF		
Gate Resistance	Rg	_	3.1	_	Ω	$f = 1.0MHz$, $V_{GS} = 0V$, $V_{DS} = 0V$	
Total Gate Charge (V _{GS} = 4.5V)	Qg	_	3.6		nC		
Total Gate Charge (V _{GS} = 10V)	Qg	_	7.7		nC	Vps = 10V. lp = 6.0A	
Gate-Source Charge	Q _{gs}	—	0.5	_	nC	$v_{\rm DS} = 10v, I_{\rm D} = 0.0A$	
Gate-Drain Charge	Q _{gd}	_	0.9		nC]	
Turn-On Delay Time	t _{D(ON)}	—	2.0	_	ns	V _{GS} = 4.5V, V _{DD} = 10V, Rg = 6Ω,	
Turn-On Rise Time	t _R	—	4.9	_	ns		
Turn-Off Delay Time	t _{D(OFF)}	_	9.9	—	ns	I _D = 6.0A	
Turn-Off Fall Time	t _F	_	3.3	—	ns	7	
Body Diode Reverse Recovery Time	t _{RR}	_	5.4	_	ns	I _F = 6.0A, di/dt = 100A/µs	
Body Diode Reverse Recovery Charge	Q _{RR}	—	0.7	_	nC	I _F = 6.0A, di/dt = 100A/µs	

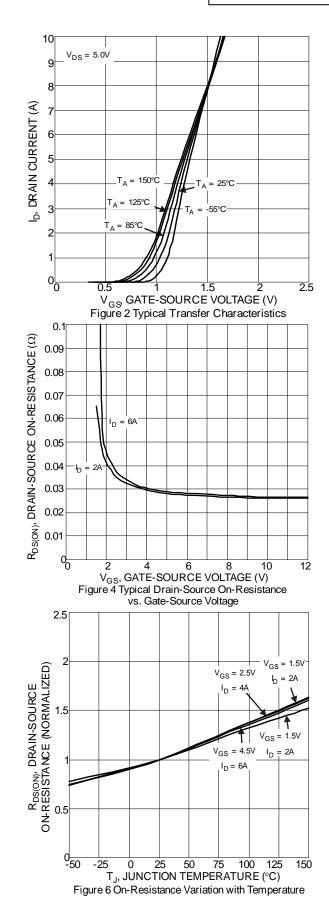
Notes:

Device mounted on FR-4 PCB, with minimum recommended pad layout.
Device mounted on 1" x 1" FR-4 PCB with high coverage 2oz. Copper, single sided.
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing.



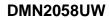
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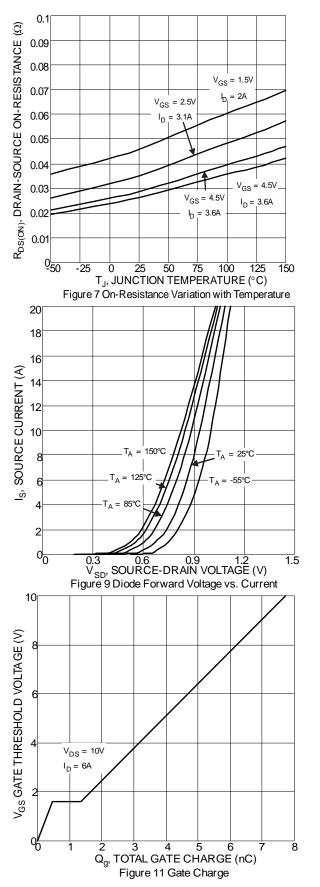


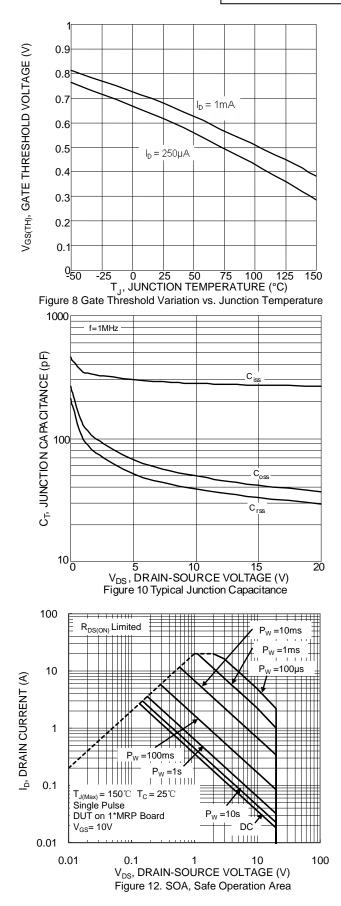


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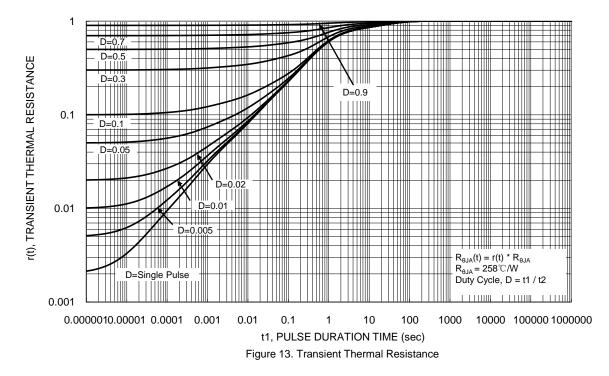






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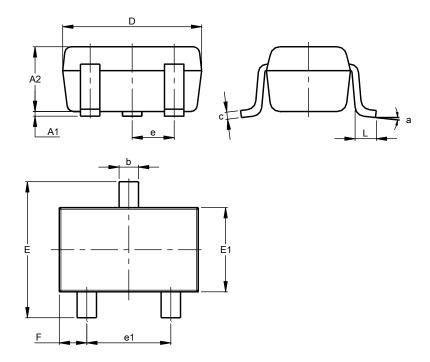




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

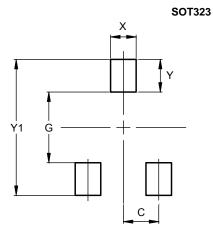
SOT323



SOT323						
Dim	Min	Max	Тур			
A1	0.00	0.10	0.05			
A2	0.90	1.00	0.95			
b	0.25	0.40	0.30			
c	0.10	0.18	0.11			
D	1.80	2.20	2.15			
Е	2.00	2.20	2.10			
E1	1.15	1.35	1.30			
е	0.650 BSC					
e1	1.20	1.40	1.30			
F	0.375	0.475	0.425			
L	0.25	0.40	0.30			
а	0°	8°				
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	0.650
G	1.300
Х	0.470
Y	0.600
Y1	2.500



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